

MIP160, MIP162, MIP163, MIP164, MIP165, MIP166

Silicon MOS IC

■ Features

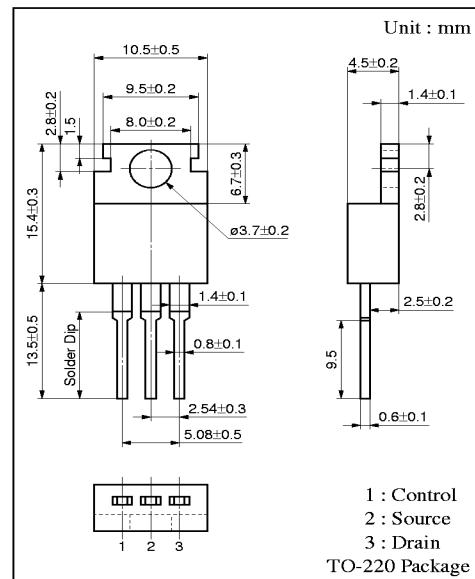
- Single chip IC with high breakdown voltage power MOS FET and CMOS control circuit
- Worldwide input (85 to 274VAC) possible
- Over-voltage protection at secondary section, pulse by pulse over-current protection, and intermittent operation timer at overload

■ Applications

- Switching mode regulator (5 to 40W)
- AC adapter
- Battery charger

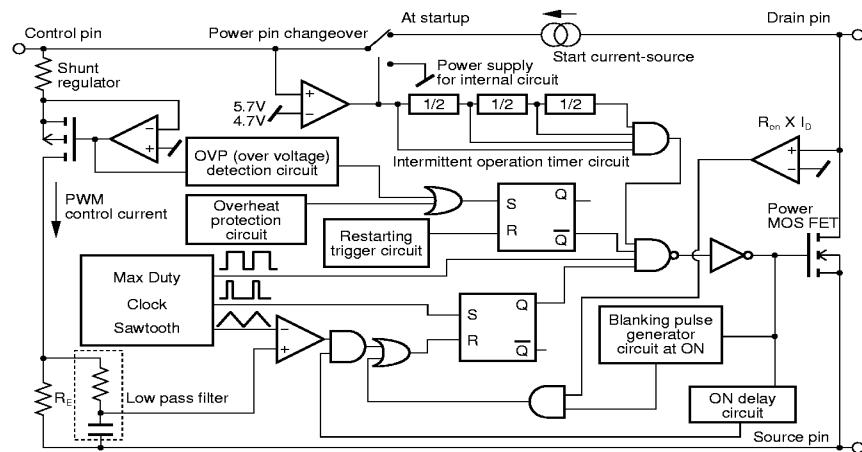
■ Absolute Maximum Ratings (Ta= 25°C)

Parameter	Symbol	Rating	Unit
Drain voltage	V _D	700	V
Control voltage	V _C	8	V
Output current	I _D	I _{LIMIT}	A
Control current	I _C	0.1	A
Allowable power dissipation	P _D	1.7/12.5 * 1	W
Operating ambient temperature	T _{opr}	- 20 to + 85	°C
Channel temperature	T _{ch}	150	°C
Storage temperature	T _{stg}	- 55 to +150	°C

* 1 : T_C= 25°C

1 : Control
2 : Source
3 : Drain
TO-220 Package

■ Block Diagram



■ Electrical Characteristics ($T_c = 25 \pm 2^\circ\text{C}$)

	Parameter		Symbol	Condition	Min	Typ	Max	Unit
Control function	Output frequency	f_{osc}	$I_C = 4\text{mA}$	90	100	110	kHz	
	Maximum duty cycle	MAXDC	$I_C = 2\text{mA}$	64	67	70	%	
	Minimum duty cycle	MINDC	$I_C = 10\text{mA}$	1	2	3	%	
Start up	Control pin charge current		I_C	$V_C = 0\text{V}$	-2.4	-1.9	-1.2	mA
				$V_C = 5\text{V}$	-2.0	-1.5	-0.8	
	Control pin voltage at startup		$V_C(\text{ON})$		5.0	5.7	6.3	V
	Control pin voltage at stop		$V_C(\text{OFF})$		4.0	4.7	5.3	V
	Start/stop hysteresis voltage		ΔV_C		0.5	1.0	1.5	V
	Intermittent operation time-ratio		T_{SW}/T_{TIM}			5	8	%
Protection function	Intermittent operation frequency		f_{TIM}		0.5	1.2	2.0	Hz
	Over current protection/detection	MIP160	I_{LIMIT}		0.415	0.5	0.585	A
		MIP162			0.75	0.9	1.05	
		MIP163			1.12	1.35	1.57	
		MIP164			1.35	1.62	1.89	
		MIP165			1.88	2.25	2.63	
		MIP166			2.4	2.8	3.2	
	Blanking width at ON		$t_{on(BLK)}$	$I_C = 4\text{mA}$		0.25		μs
	Over current protection delay time		$t_d(OCL)$	$I_C = 4\text{mA}$		0.1		μs
	Over current protection temperature		T_{OTP}	$I_C = 4\text{mA}$	130	140	150	$^\circ\text{C}$
	Over voltage protection/detection current		I_{ovp}		25	45	75	mA
Output	Latch reset voltage		$V_C(\text{reset})$		2.3	3.3	4.2	V
	ON resistance	MIP160	$R_{DS(ON)}$	0.1A		15	18	Ω
		MIP162		0.3A		8.5	10	
		MIP163		0.3A		5.8	6.7	
		MIP164		0.5A		4.5	5.5	
		MIP165		0.8A		3.0	3.8	
		MIP166		1.0A		2.6	3.3	
	Drain pin leak current at OFF		I_{DSS}	$V_{DS} = 650\text{V}, I_C = 4\text{mA}$ latch mode		0.5	0.9	mA
	Drain breakdown voltage		V_{DSS}	$I_C = 4\text{mA}, I_D = 0.25\text{mA}$ latch mode	700			V
	Rise time		t_f			0.1	0.2	μs
Supply voltage	Fall time		t_r			0.1	0.2	μs
	Minimum drain voltage		$V_{D(MIN)}$		36			V
	Shunt regulator voltage		V_C	$I_C = 4\text{mA}$	5.5	5.8	6.1	V
	Control pin discharge current		I_{CD1}	at output MOS operation	0.7	1.4	1.8	mA
			I_{CD2}	at output MOS stop	0.5	0.8	1.1	mA

